

NE3520S03

Data Sheet R09DS0029EJ0100 Rev.1.00 Oct 18, 2011

N-Channel GaAs HJ-FET, K Band Low Noise and High-Gain

FEATURES

- Low noise figure and high associated gain: NF = 0.65 dB TYP., G_a = 13.5 dB TYP. @ f = 20 GHz, V_{DS} = 2 V, I_D = 10 mA
- K band Micro-X plastic (S03) package

APPLICATIONS

- 20 GHz band DBS LNB
- Other K band communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3520S03-T1C	NE3520S03-T1C-A	S03 package	2 kpcs/reel	J	 Embossed tape 8 mm wide
		(Pb-Free)			Pin 4 (Gate) face the
					perforation side of the tape
NE3520S03-T1D	NE3520S03-T1D-A		10 kpcs/reel		p

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: NE3520S03-A

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	V _{DS}	4.0	V
Gate to Source Voltage	V_{GS}	-3.0	V
Drain Current	I_{D}	I _{DSS}	mA
Gate Current	I _G	100	μΑ
Total Power Dissipation Note	P _{tot}	165	mW
Channel Temperature	T _{ch}	+125	°C
Storage Temperature	T _{stg}	-65 to +125	°C

Note: Mounted on 1.08 cm² × 1.0 mm (t) glass epoxy PWB



Observe precautions when handling because these devices are sensitive to electrostatic discharge.

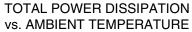
RECOMMENDED OPERATING RANGE ($T_A = +25^{\circ}C$, unless otherwise specified)

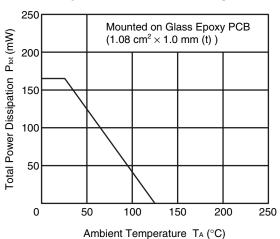
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	V _{DS}	+1	+2	+3	V
Drain Current	I _D	5	10	15	mA
Input Power	P _{in}	_	_	0	dBm

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

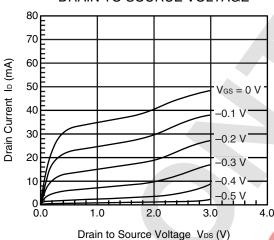
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Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I _{GSO}	V _{GS} = -3.0 V	-	0.5	10	μΑ
Saturated Drain Current	I _{DSS}	V _{DS} = 2 V, V _{GS} = 0 V	25	40	70	mA
Gate to Source Cut-off Voltage	V _{GS (off)}	$V_{DS} = 2 \text{ V}, I_{D} = 100 \mu\text{A}$	-0.2	-0.7	-1.3	>
Transconductance	gm	V _{DS} = 2 V, I _D = 10 mA	50	65	/	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 10 mA, f = 20 GHz	-	0.65	0.90	dB
Associated Gain	Ga		11.5	13.5	_	dB

TYPICAL CHARACTERISTICS ($T_A = +25^{\circ}C$, unless otherwise specified)

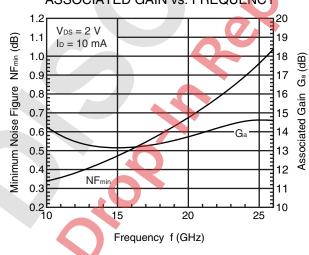




DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE

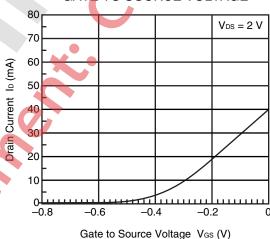


MINIMUM NOISE FIGURE,
ASSOCIATED GAIN vs. FREQUENCY

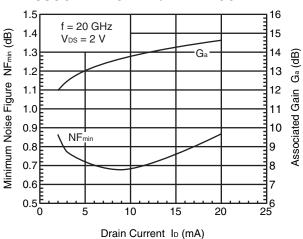


Remark The graphs indicate nominal characteristics.





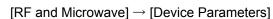
MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN CURRENT



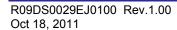
S-PARAMETERS

S-parameters/Noise-parameters are provided on our web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

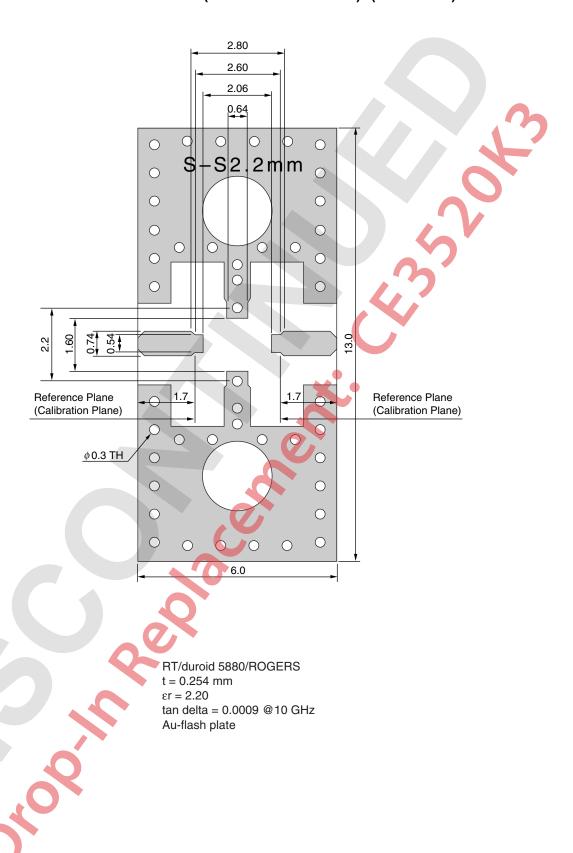
Click here to download S-parameters.



URL http://www2.renesas.com/microwave/

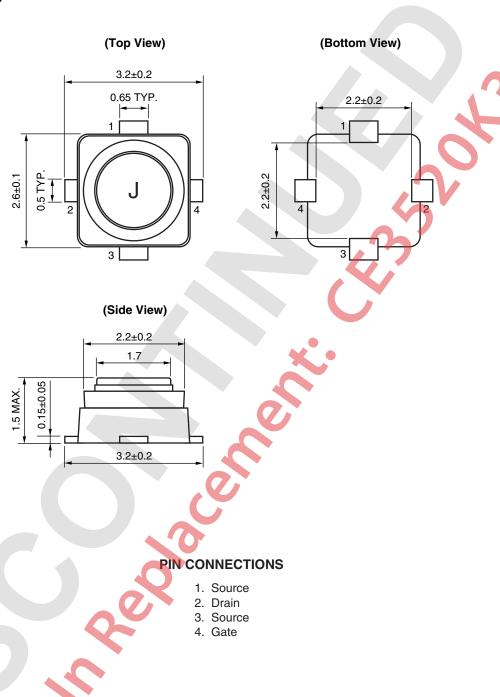


RF MEASURING LAYOUT PATTERN (REFERENCE ONLY) (UNIT: mm)



PACKAGE DIMENSIONS

S03 (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).





Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.



Revision	History

NE3520S03 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Oct 18, 2011	-	First edition issued	



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011086 QPD1014SR T2G6000528-Q3 CG2H40025F CGHV40200PP CGHV40050F CGHV14800F CGH27030P CGH09120F

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